

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









Three Phase Half Controlled Rectifier Bridge

| 2 0- | | 3 | |
|--------------|--------|----|---|
| 20- | \Box | ک] | 4 |
| | 4 | ΣŽ | P |
| 5 O - | —• | , | ı |

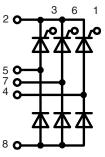
| I_{dAVM} | =43 A | |
|---------------------------|-------------|---|
| \mathbf{V}_{RRM} | = 1200-1600 | V |

| V _{RSM} V _{DSM} | V _{RRM} V _{DRM} | Туре |
|--------------------------------------|--------------------------------------|--------------|
| 1300 | 1200 | VVZ 40-12io1 |
| 1500 | 1400 | VVZ 40-14io1 |
| 1700 | 1600 | VVZ 40-16io1 |

Conditions

 $di_{G}/dt = 0.3 A/\mu s$

Symbol



Maximum Ratings

| 1 2 3 4 7 8 |
|-----------------|
| % E72873 |

| - | | | | • |
|-------------------------------------|---|--|-----|------------------|
| I _{dAV} | T _K = 100°C; modul | le | 34 | A |
| I _{dAVM} | module | | 43 | Α |
| $I_{\text{FRMS}}, I_{\text{TRMS}}$ | per leg | | 25 | Α |
| I _{FSM} , I _{TSM} | $T_{VJ} = 45^{\circ}C;$ | t = 10 ms (50 Hz), sine | 320 | Α |
| | $V_R = 0$ | t = 8.3 ms (60 Hz), sine | 340 | Α |
| | $T_{VJ} = T_{VJM}$ | t = 10 ms (50 Hz), sine | 290 | Α |
| | $V_R = 0$ | t = 8.3 ms (60 Hz), sine | 310 | Α |
| l²t | T _{v,j} = 45°C | t = 10 ms (50 Hz), sine | 510 | A ² s |
| | $V_R = 0$ | t = 8.3 ms (60 Hz), sine | 485 | A ² s |
| | $T_{V,I} = T_{V,IM}$ | t = 10 ms (50 Hz), sine | 420 | A ² s |
| | $V_R = 0$ | t = 8.3 ms (60 Hz), sine | 400 | A^2s |
| (di/dt) _{cr} | $T_{V,I} = T_{V,IM}$ | repetitive, $I_T = 50 \text{ A}$ | 150 | A/μs |
| | $f = 400 \text{ Hz}, t_P = 200 \mu\text{s}$ | | | |
| | $V_D = 2/3 V_{DRM}$ | | | |
| | $I_{c} = 0.3 A$ | non repetitive, $I_{\tau} = 1/3 \cdot I_{day}$ | 500 | A/us |

| (dv/dt) _{cr} | $T_{VJ} = T_{VJM}; V_{DR} = 2$ | = | 1000 | V/μs |
|-----------------------|--------------------------------|------------------------|---------|--------|
| | H _{GK} = ∞, method i | (linear voltage rise) | | |
| V_{RGM} | | | 10 | V |
| P _{GM} | $T_{VJ} = T_{VJM}$ | t _p = 30 μs | ≤ 10 | W |
| | $I_T = I_{TAVM}$ | $t_{p} = 500 \mu s$ | ≤ 5 | W |
| | | $t_n = 10 \text{ ms}$ | ≤ 1 | W |
| \mathbf{P}_{GAVM} | | r | 0.5 | W |
| T _{VJ} | | | -40+125 | °C |
| T_{VJM} | | | 125 | °C |
| T_{stg} | | | -40+125 | °C |
| V _{ISOL} | 50/60 Hz, RMS | t = 1 min | 3000 | V~ |
| | $I_{ISOL} \le 1 \text{ mA}$ | t = 1 s | 3600 | V~ |
| M _d | Mounting torque | (M5) | 2-2.5 | Nm |
| - | • | (10-32 UNF) | 18-22 | lb.in. |
| Weight | typ. | , , | 28 | g |

Data according to IEC 60747 and refer to a single thyristor/diode unless otherwise stated.

Features

- · Package with DCB ceramic base plate
- Isolation voltage 3600 V~
- Planar passivated chips
- · Soldering terminals
- UL registered E 72873

Applications

- Input rectifier for switch mode power supplies (SMPS)
- · Softstart capacitor charging
- · Electric drives and auxiliaries

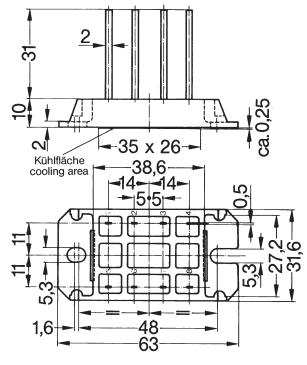
Advantages

- Easy to mount with two screws
- Space and weight savings
- · Improved temperature and power cycling



| Symbol | Conditions Chara | | Characteris | acteristic Values | | |
|---------------------------------------|--|--|---------------|-------------------|-------------------|--|
| I _R , I _D | $V_R = V_{RRM}; V_D = V_{DRM}$ | $T_{VJ} = T_{VJM}$ $T_{VJ} = 25^{\circ}C$ | ≤ ≤ | 5 0.3 | mA mA | |
| V_F, V_T | I_F , $I_T = 30 A$, $T_{VJ} = 25^{\circ}$ | | <u>≤</u> | 1.33 | V | |
| V _{T0} | For power-loss calcula (T _{VJ} = 125°C) | ations only | | 0.85 15 | V mΩ | |
| V _{GT} | $V_{D} = 6 \text{ V};$ $V_{D} = 6 \text{ V};$ | $T_{VJ} = 25^{\circ}C$ $T_{VJ} = -40^{\circ}C$ $T_{VJ} = -35^{\circ}C$ | ≤ ≤ ≤ | 1.0 1.2 65 | V V | |
| I _{GT} | $v_D = o v$, | $T_{VJ} = 25^{\circ}C$ $T_{VJ} = -40^{\circ}C$ $T_{VJ} = 125^{\circ}C$ | \le \(\le \) | 80 50 | mA mA | |
| V _{GD} I _{GD} | $T_{VJ} = T_{VJM};$ $T_{VJ} = T_{VJM};$ | $V_D = 2/3 V_{DRM}$ $V_D = 2/3 V_{DRM}$ | ≤ ≤ | 0.2 5 | V mA | |
| I _L | $I_{\rm G} = 0.3 \; {\rm A}; \; t_{\rm G} = 30 \; \mu {\rm S}$ $di_{\rm G}/dt = 0.3 \; {\rm A}/\mu {\rm S}$ | $T_{VJ} = 25^{\circ}C$ $T_{VJ} = -40^{\circ}C$ $T_{VJ} = 125^{\circ}C$ | ≤ ≤ ≤ | 150 200 100 | mA mA mA | |
| I _H | $T_{VJ} = 25^{\circ}C; V_{D} = 6 V; F$ | R _{GK} = ∞ | ≤ | 100 | mA | |
| t _{gd} | $T_{VJ} = 25^{\circ}C; V_D = 1/2 V_D$ $I_G = 0.3 A; di_G/dt = 0.3$ | D1 1141 | ≤ | 2 | μs | |
| t _q Q _r | $T_{VJ} = 125^{\circ}C; I_{T} = 15 \text{ A}, t_{p} = 300 \mu\text{s}, -\text{di/dt} = 10 \text{ A/}\mu\text{s}$ $V_{R} = 100 \text{ V}, \text{dv/dt} = 20 \text{ V/}\mu\text{s}, V_{D} = 2/3 \text{ V}_{DRM}$ | | /μs typ | . 150 75 | μs μC | |
| R _{thJC} | per thyristor (diode); DC current per module per thyristor (diode); DC current per module | | | 0.17 1.6 | K/W K/W K/W | |
| d _s d _a a | Creeping distance on Creepage distance in Max. allowable accele | air | | 7 7 50 | mm mm m/s² | |

Dimensions in mm (1 mm = 0.0394")



IXYS reserves the right to change limits, test conditions and dimensions.